FORM PTO-1449 (Modified)												SERIAL NO. 09/088,065			
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT								APPLICANT: A. Okamoto							
(Use several sheets if necessary)								·				GROUP 3743			
REFERE	NCE	DES	SIGN	ATION		U.S. PA	CENT I	DOCUMEN	TS						
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				4,707,412		11/17/87									
		_		5,095,384		03/10/92						-DEC			
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are		+	_	5,669,584		09/23/97						MAY	1 1999		
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OF		EP 0 526 767 A1 02/10/93			EP	0				Abstract					
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Hashimoto et al. "Crystal growth and characterization of La1-xMxMn03(M=Ca,Sr)" 2, August 1987, pages 207-211, XP002005875, Amsterdam, Netherlands)", Joui	rnal of Crystal G	rowth, vol. 84, no.							
at		2		Search report from EPO, ref. no. N1495070EPP00Sk, dated February 17, 1999											
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EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through

citation if not conformance and not considered. Include copy of this form with next communication to applicant,

				Docket Number (Optional)	^	Application Number 09/198,376				
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				OTHER	DOCUMENTS (Including	Author, Title,	Date, Pertinent P	ages, Etc.)	·	
AF	,	European Office Act	ion dated 8-18-03							
AF		Article titled "Understanding doped V/sub 2/0/sub 3/ as a functional positive temperature coefficient material" Authors: Hendrix, Chen, Wang and Cui dated 6-92								
EXAMINER /Allen Flanigan/					DATE CONSIDERED	06/2	9/2006			
EXAMINI not consid	ER: Init	tial if citation considered, whet nclude copy of this form with n	her or not citation is in ext communication to	n conforma applicant.	nce with MPEP Section 609; C)raw line thro	ugh citation if no	ot in conform	ance and	

Form PTO-A820 (also form PTO-1449) POBA/REVO4

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